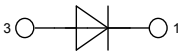
Sonic Fast Recovery Diode

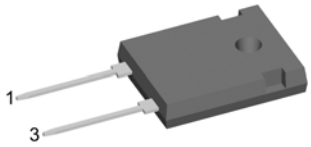
V_{RRM} = 1800 V
I_{FAV} = 60 A
t_{rr} = 230 ns

High Performance Fast Recovery Diode
Low Loss and Soft Recovery
Single Diode

Part number

DH60-18A





Backside: cathode

Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package:

- Housing: TO-247
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

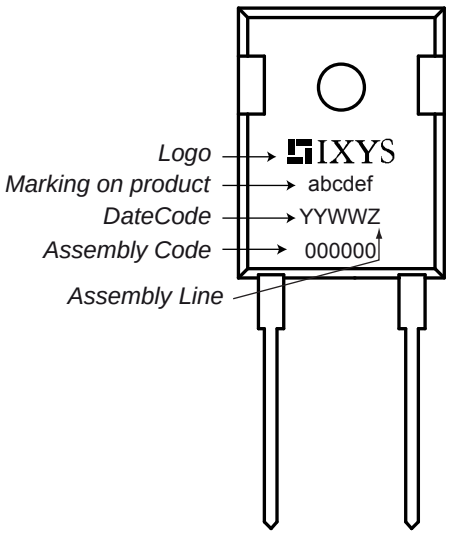
Ratings

Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RRM}	*max. repetitive reverse voltage*		T_{VJ} = 25°C			1800	V
I_R	*reverse current*	V_R = 1800 V	T_{VJ} = 25°C			200	µA
		V_R = 1800 V	T_{VJ} = 125°C			2	mA
V_F	*forward voltage*	I_F = 60 A	T_{VJ} = 25°C			2.04	V
		I_F = 120 A				2.57	V
		I_F = 60 A	T_{VJ} = 125°C			2.05	V
		I_F = 120 A				2.78	V
I_{FAV}	*average forward current*	rectangular d = 0.5	T_C = 100°C			60	A
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 150°C			1.28	V
r_F	*slope resistance* }					12	mΩ
R_{thJC}	*thermal resistance junction to case*					0.30	K/W
T_{VJ}	*virtual junction temperature*			-55		150	°C
P_{tot}	*total power dissipation*		T_C = 25°C			415	W
I_{FSM}	*max. forward surge current*	t = 10 ms (50 Hz), sine	T_{VJ} = 45°C			700	A
I_{RM}	*max. reverse recovery current*		T_{VJ} = 25°C		60		A
		I_F = 60 A; V_R = 1200 V	T_{VJ} = 100°C		70		A
t_{rr}	*reverse recovery time*	$-di_F/dt$ = 800 A/µs	T_{VJ} = 25°C		230		ns
			T_{VJ} = 100°C		350		ns
C_J	*junction capacitance*	V_R = 1200 V; f = 1 MHz	T_{VJ} = 25°C		32		pF

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Symbol	Definition	Conditions	Ratings min.	typ.	max.	Unit
I_{RMS}	*RMS current*	per terminal			70	A
R_{thCH}	*thermal resistance case to heatsink*			0.25		K/W
T_{stg}	*storage temperature*		-55		150	°C
Weight				6		g
M_D	*mounting torque*		0.8		1.2	Nm
F_C	*mounting force with clip*		20		120	N

Product Marking

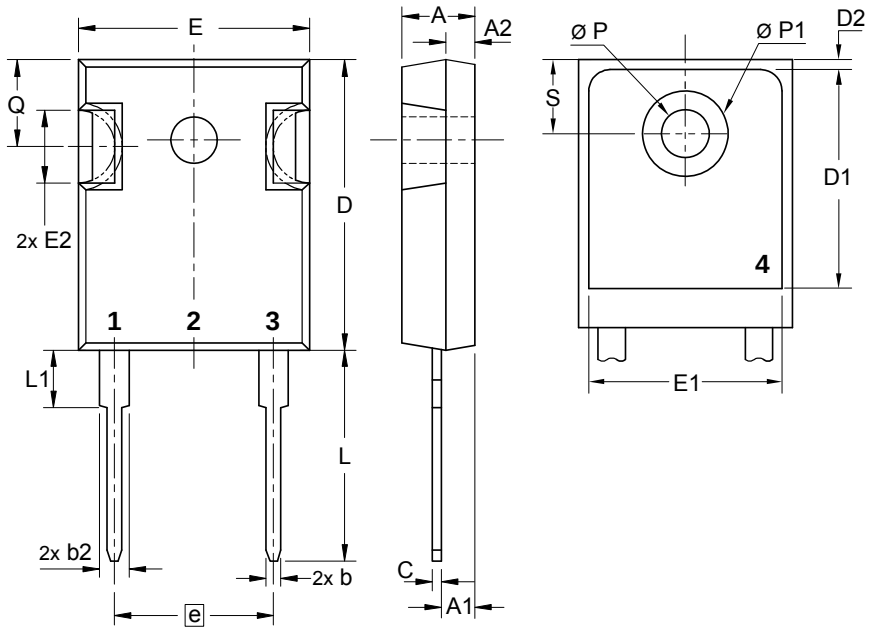


Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DH60-18A	DH60-18A	Tube	30	496553

Similar Part	Package	Voltage Class
DH60-14A	TO-247AD (2)	1400
DH60-16A	TO-247AD (2)	1600

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Outlines TO-247



Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.430 BSC		10.92 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39

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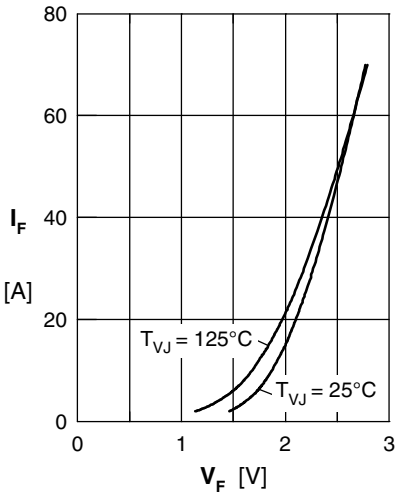


Fig. 1 Typ. rward current I_F versus V_F

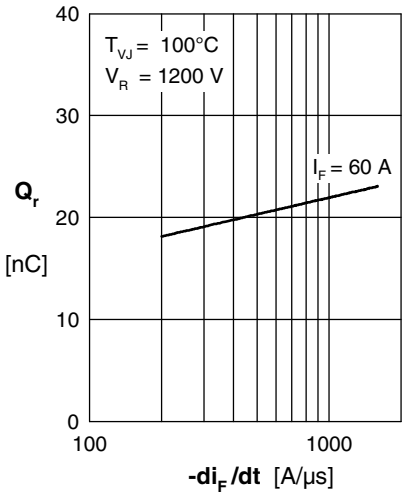


Fig. 2 Typ. reverse recovery charge Q_r versus $-di_F/dt$

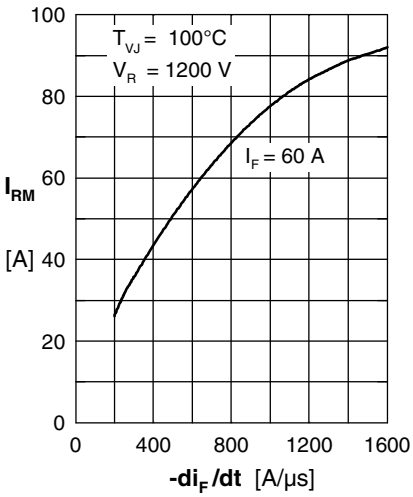


Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

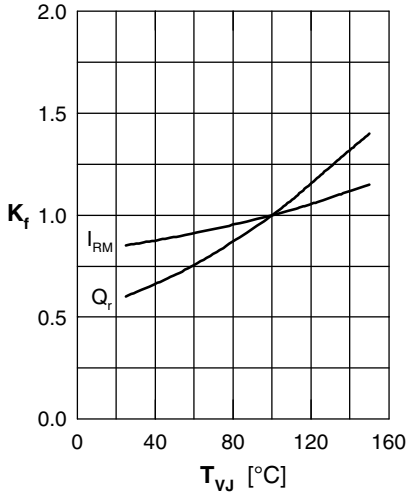


Fig. 4 Dynamic parameters Q_r, I_{RM} versus T_{VJ}

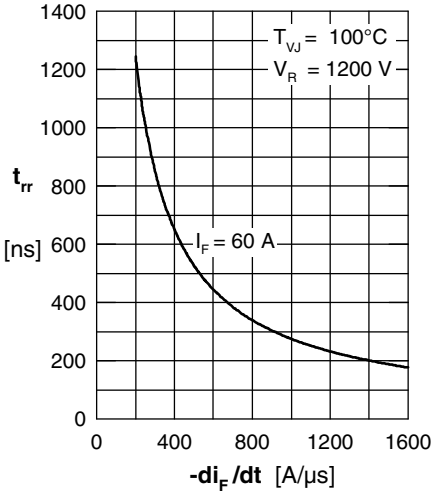


Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$

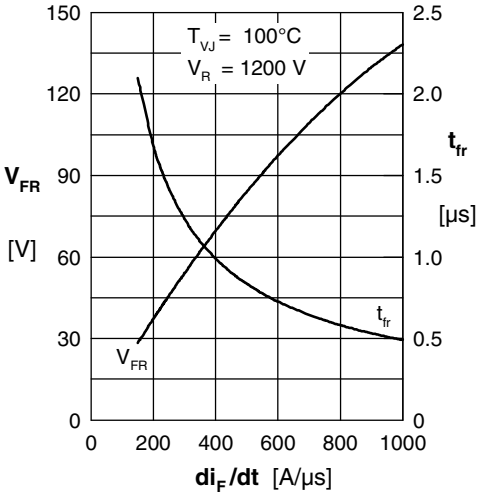
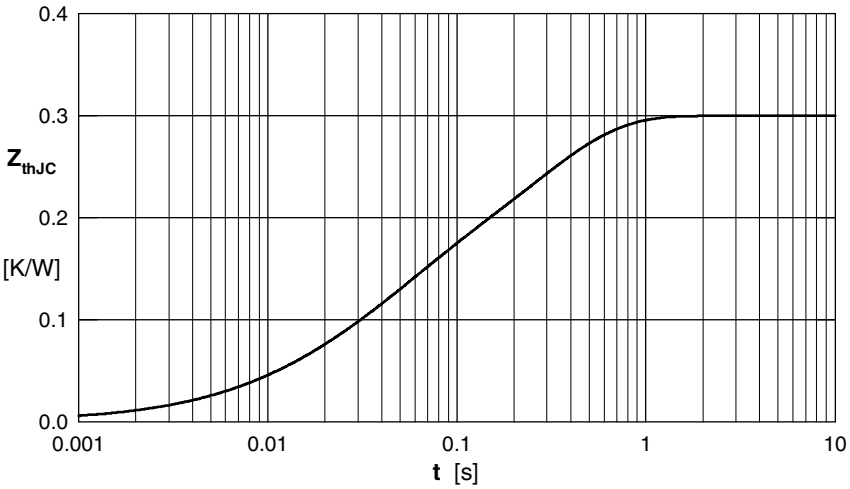


Fig. 6 Typ. peak forward voltage V_{FR} & typ. forward recovery time t_{fr} versus di_F/dt



i	R_i	τ_i
1	0.021	0.0093
2	0.11	0.038
3	0.169	0.274

Fig. 7 Transient thermal resistance junction to case

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